

FGW75N60HD

Discrete IGBT

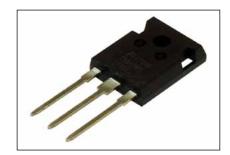
Discrete IGBT (High-Speed V series) 600V / 75A

■ Features

Low power loss Low switching surge and noise High reliability, high ruggedness (RBSOA, SCSOA etc.)

Applications

Uninterruptible power supply Power coditionner Power factor correction circuit

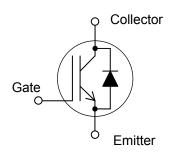


■ Maximum Ratings and Characteristics

● Absolute Maximum Ratings (at T_c=25°C unless otherwise specified)

| Items | Symbols | Characteristics | Units | Remarks | | |
|---------------------------------------|---------------------|-----------------|-------|--|--|--|
| Collector-Emitter voltage | Vces | 600 | V | | | |
| Gate-Emitter voltage | V _{GES} | ±20 | V | | | |
| DC Collector Current | Ic@25 | 100 | Α | T _c =25°C, T _i =150°C Note *1 | | |
| | Ic@100 | 75 | Α | Tc=100°C, Tj=150°C | | |
| Pulsed Collector Current | I _{CP} | 225 | Α | Note *2 | | |
| Turn-Off Safe Operating Area | - | 225 | Α | Vce≤600V, Tj≤175°C | | |
| Diode Forward Current | I _{F@25} | 60 | Α | Note *1 | | |
| | IF@100 | 35 | Α | | | |
| Diode Pulsed Current | I _{FP} | 225 | Α | Note *1 | | |
| Short Circuit Withstand Time | tsc | 5 | μs | Vcc≤300V, VgE=12V Tj≤175°C | | |
| IGBT Max. Power Dissipation | P _{D_IGBT} | 500 | W | Tc=25°C | | |
| FWD Max. Power Dissipation | P _{D_FWD} | 190 | ۷V | Tc=25°C | | |
| Operating Junction Temperature | T _j | -40~+175 | °C | | | |
| Storage Temperature | T _{stg} | -55~+175 | °C | | | |

Equivalent circuit



Note *1 : Current value limited by bonding wire. Note *2 : Pulse width limited by Tjmax.

● Electrical characteristics (at T_i= 25°C unless otherwise specified)

| Hama | Cumbala | Combala Candidiana | | | Characteristics | | |
|--------------------------------------|-----------------------|--|--|--------|-----------------|------|-------|
| Items | Symbols | Conditions | | min. | typ. | max. | Units |
| Collector-Emitter Breakdown Voltage | V _{(BR)CES} | Ic = 250μA, V _{GE} = 0V | | 600 | - | - | V |
| Zero Gate Voltage Collector Current | Ices | V _{CE} = 600V, V _{GE} = 0V | T _j =25°C | - | - | 250 | μA |
| | ICES | | T _j =175°C | - | - | 10 | mA |
| Gate-Emitter Leakage Current | Iges | $V_{CE} = 0V, V_{GE} = \pm 20V$ | | - | - | 200 | nA |
| Gate-Emitter Threshold Voltage | V _{GE (th)} | $V_{CE} = +20V$, $I_{C} = 75mA$ | | 4.0 | 5.0 | 6.0 | V |
| Collector-Emitter Saturation Voltage | V _{CE} (sat) | V _{GE} = +15V, I _C = 75A | T _j =25°C | - | 1.50 | 1.95 | V |
| | | | T _j =175°C | - | 1.80 | - | v |
| Input Capacitance | Cies | Vc=25V Vc=0V f=1MHz | | - | 6150 | - | pF |
| Output Capacitance | Coes | | | - | 300 | - | |
| Reverse Transfer Capacitance | Cres | | | - | 240 | - | |
| | | Vcc = 400V | | | | | |
| Gate Charge | Q _G | Ic = 75A | Ic = 75A | | 460 | - | nC |
| | | V _{GE} = 15V | | | | | |
| Turn-On Delay Time | t _{d(on)} | T _j = 25°C | | - | 45 | - | |
| Rise Time | t | Vcc = 400V | - | 130 | - | ns | |
| Turn-Off Delay Time | t _{d(off)} | Ic = 75A | - | 450 | - | | |
| Fall Time | tr | V _{GE} = 15V | - | 105 | - | | |
| Turn-On Energy | Eon | $R_G = 10\Omega$ | | - | 3.0 | - | |
| | | L = 500µH | | | | | mJ |
| Turn-Off Energy | Eoff | Energy loss include "tail" a | Energy loss include "tail" and FWD reverse | | 4.2 | - | 1113 |
| | | recovery. | | | | | |
| Turn-On Delay Time | t _{d(on)} | T _i = 175°C | | - 45 - | | | |
| Rise Time | t | Vcc = 400V | | - | 130 | - | ns |
| Turn-Off Delay Time | t _{d(off)} | Ic = 75A | - | 490 | - | | |
| Fall Time | tr | V _{GE} = 15V | | - | 120 | - | |
| Turn-On Energy | Eon | $R_G = 10\Omega$ | | - | 4.3 | - | |
| · | | L = 500µH | | | | | mJ |
| Turn-Off Energy | Eoff | Energy loss include "tail" and FWD reverse | | - | 4.8 | - | 1110 |
| | | recovery. | | | | | |

http://www.fujielectric.com/products/semiconductor/

● FWD Characteristics

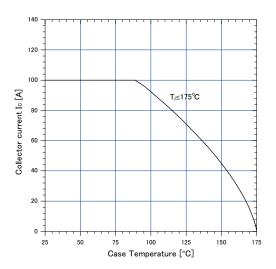
| Description | Cumbal | Canditions | Conditions | | Characteristics | | |
|-------------------------------|------------------|-------------------------------|-----------------------|---|-----------------|------|------|
| Description | Symbol | Conditions | | | typ. | max. | Unit |
| Forward Voltage Drop | VF | I _F =35A | T _j =25°C | - | 2.0 | 2.6 | V |
| Forward Voltage Drop | VF | IF-35A | T _j =175°C | - | 1.4 | - | V |
| Diode Reverse Recovery Time | + . | Vcc=30V,I _F = 3.5A | | _ | 26 | 36 | ns |
| | Lrr1 | -di/dt=200A/µs | | _ | | | 113 |
| Diode Reverse Recovery Time | t _{rr2} | Vcc=400V | | | 0.05 | _ | μs |
| Diode Reverse Recovery Time | UTZ | I⊧=35A | | | 0.00 | _ | μο |
| Diode Reverse Recovery Charge | Qrr | -di _ε /dt=200A/μs | | _ | 0.12 | _ | μC |
| | <u> </u> | T _j =25°C | | | 0 | | |
| Diode Reverse Recovery Time | t _{rr2} | Vcc=400V | | _ | 0.19 | _ | μs |
| | U.Z | I⊧=35A | | | 00 | | |
| Diode Reverse Recovery Charge | Qrr | -di⊧/dt=200A/µs | | _ | 1.10 | _ | uС |
| | G'' | T _i =175°C | | | 10 | | ا ۳۰ |

● Thermal resistance characteristics

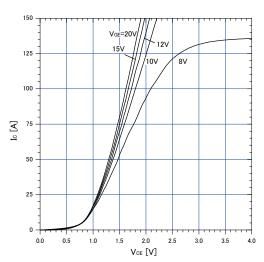
| Items | Symbols | Conditions | Characteristics | | | Units |
|---|---------------------------|------------|-----------------|------|-------|--------|
| | | | min. | typ. | max. | Ullits |
| Thermal Resistance, Junction-Ambient | R _{th(j-a)} | - | - | - | 50 | |
| Thermal Resistance, IGBT Junction to Case | R _{th(j-c)_IGBT} | - | - | - | 0.298 | °C/W |
| Thermal Resistance, FWD Junction to Case | R _{th(j-c)_FWD} | - | - | - | 0.781 | |

■ Characteristics (Representative)

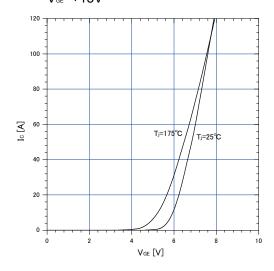
Graph.1 DC Collector Current vs T_{c} $V_{cg} \ge +15V$, $T_{i} \le 175^{\circ}C$



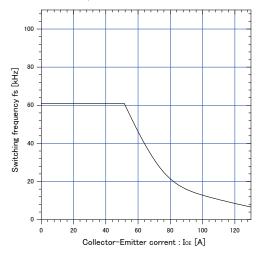
Graph.3
Typical Output Characteristics (V_{CE}-I_C)
T,=25°C



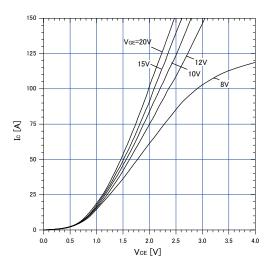
Graph.5 Typical Transfer Characteristics V_{GE} =+15V



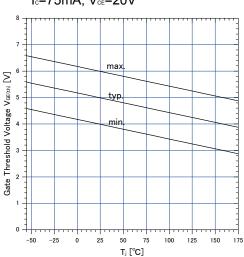
Graph.2 Collector Current vs. switching frequency V_{ce} =+15V, T_{c} ≤175°C, V_{cc} =400V, D=0.5, R_{e} =10 Ω , T_{c} =100°C



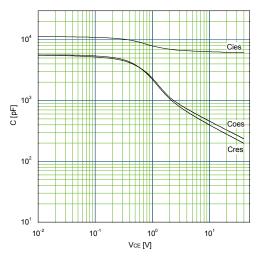
Graph.4
Typical Output Characteristics (VcE-Ic)
T_j=175°C



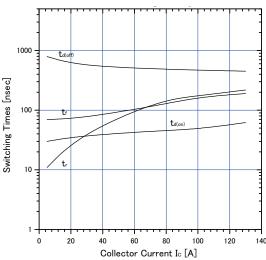
Graph.6
Gate Threshold Voltage vs. T_i
I₀=75mA, V₀_E=20V



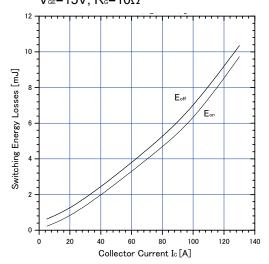
Graph.7 Typical Capacitance V_{c∈}=0V, f=1MHz, T_i=25°C



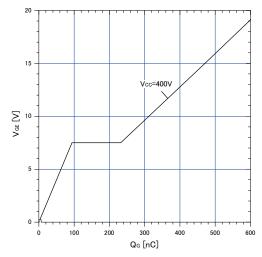
Graph.9 Typical switching time vs. I_c T_J=175°C, V_{cc} =400V, L=500 μ H V_{ee} =15V, R_e =10 Ω



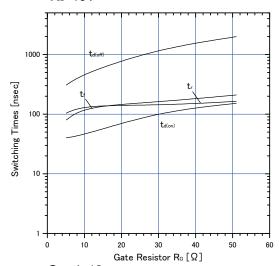
Graph.11 Typical switching losses vs. I_c T_i =175°C, V_{cc} =400V, L=500 μ H V_{ce} =15V, R_c =10 Ω



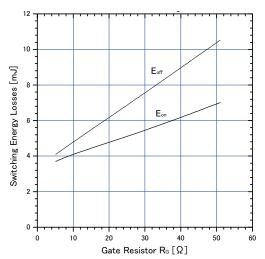
Graph.8 Typical Gate Charge Vcc=400V, Ic=75A, T,=25°C



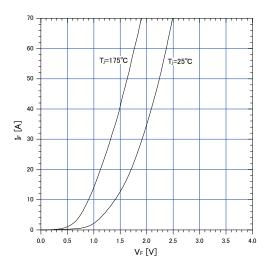
Graph.10 Typical switching time vs. R_s T_j =175°C, V_{cc} =400V, I_c =75A, L=500 μ H V_{se} =15V



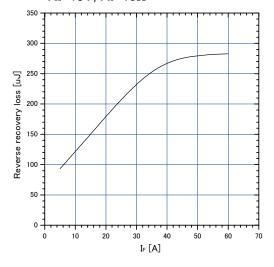
Graph.12 Typical switching losses vs. $R_{\rm s}$ T,=175°C, $V_{\rm cc}$ =400V, $I_{\rm c}$ =75A, L=500 μ H $V_{\rm se}$ =15V



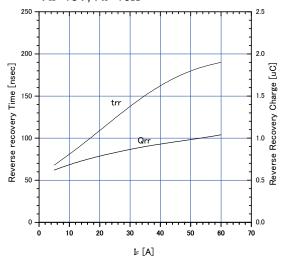
Graph.13 FWD Forward voltage drop (V_F-I_F)



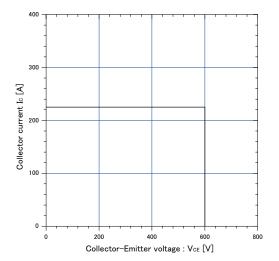
Graph.15 Typical reverse recovery loss vs. I_F $T_r=175^{\circ}C$, $V_{cc}=400V$, $L=500\mu H$ $V_{ce}=15V$, $R_c=10\Omega$



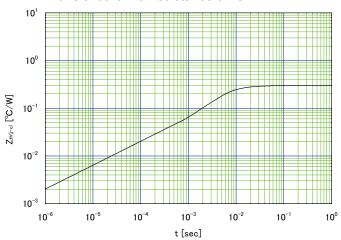
Graph.14 Typical reverse recovery characteristics vs. I_{F} T_{J} =175°C, V_{cc} =400V, L=500 μH V_{ce} =15V, R_{c} =10 Ω



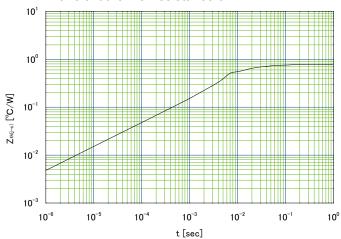
Graph.16 Reverse biased Safe Operating Area $T_i \le 175^{\circ}C$, $V_{\text{GE}} = +15 \text{V/OV}$, $R_{\text{G}} = 10 \Omega$



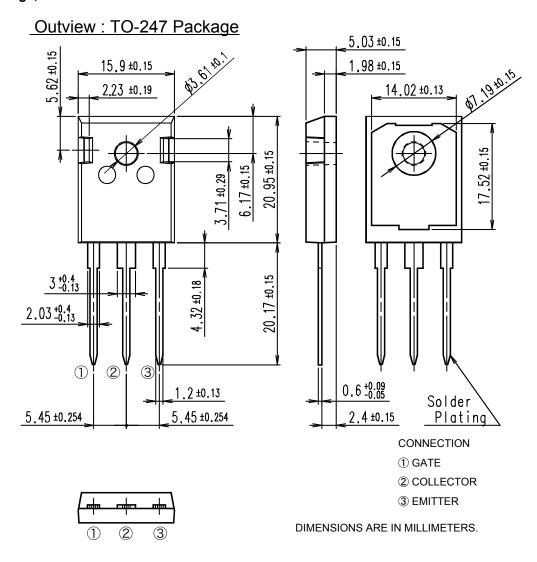
Graph.17
Transient thermal resistance of IGBT



Graph.18
Transient thermal resistance of FWD



■ Outline Drawings, mm



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